# A-465

USA Model (former and new types) E Model AFP Model



# INTEGRATED STEREO AMPLIFIER

100W (8 Ω)

90W (4.0)

### SPECIFICATIONS

GENERAL

System:

Power amplifier section: direct-coupled pure complementary symmetry circuitry

Preamplifier:

direct-coupled two-stage phono, flat and negative feed-back control

Power Requirements:

circuitry 120 V ac, 60 Hz (USA model) 110, 127, 220 or 240 V ac, 50/60 Hz,

adjustable (AEP, model) 100, 120, 220 or 240 V ac, 50/60 Hz, adjustable (E model)

270W (by IEC Standard)

Power Consumption:

Dimensions:

approx 460(w) x 168(h) x 323(d) mm, 18½ x 65/s x 12¾ inches (AEP model) 430(w) x 168(h) x 323(d) mm, 16% x 65% x 1234 inches (E, USA model)

including projecting parts and controls

Weight: annrox prox. 12.4 kg, 27 lb 5 oz (AEP model) in net 11.5 kg, 25 lb 6 oz (E, USA model) 15.2 kg, 33 lb 8 oz with shipping carton (AEP model)

13.6 kg, 30 lb (E, USA model)

POWER AMPLIFIER SECTION

Continuous RMS Power Output: (less than 0.1% THD, both channels driven simultaneously)

at 1 kHz 35 + 35 W (8 Ω) 30+30W (4Ω)

at 20 – 20,000 Hz 30 + 30 W (8 Ω)

according to DIN 45500 35 + 35 W

Dynamic Power Output: (IHE constant power

supply method) Power Bandwidth

(IHF): 5 Hz - 70 kHz less than 0.1 % at rated output Harmonic Distortion:

Intermodulation (IM) Distortion: (60 Hz: 7 kHz = 4:1)

Frequency Response: (at 1 W output)

> S/N ratio: Residual Noise:

> Damping Factor:

45 (8 Ω, at 1 kHz) POWER INPUT Inputs: Outputs:

sensitivity 1 V RMS (for rated output) impedance 50 kΩ SPEAKER terminals A, B

less than 0.005 μW (8 Ω)

2 Hz - 100 kHz +0 dB

input

accept speakers of 4 \Omega or more HEADPHONE jack accepts low-and high-impedance stereo headphones

less than 0.05 % at 1 W output

less that 0.1 % at rated output

less than 0.05 % at 1 W output

greater than 110 dB, short-circuited

(Continued on next page.)

SONY SERVICE MANUAL

#### PREAMPLIFIER SECTION

Harmonic Distortion:

less than 0.05 % at rated output

Intermodulation (IM) Distortion: (60 Hz: 7 kHz = 4:1)

less than 0.05 % at rated output

Frequency response:

PHONO 1, 2 RIAA equalization ±0.5 dB

(input)

TUNER AUX 1, 2
TAPE 1, 2
TAPE 1, 2
TAPE 1, 2
TAPE 1, 2
TAPT 1, 2
EXT ADPT 1, 2

Tone Controls:

BASS:

±10dB at 50Hz (TURNOVER 250Hz) ±10dB at 100Hz (TURNOVER 500Hz) TREBLE:

±10dB at 10kHz (TURNOVER 2.5kHz) ±10dB at 20kHz (TURNOVER 5kHz)

LOW:

Filters: 6 dB/octave attenuation below 35 Hz 6 dB/octave attenuation above 6 kHz

Loudness Switch: (att. 30 dB)

+10 dB at 50 Hz +3 dB at 10 kHz

#### Inputs

	Sensitivity	Impedance	Maximum input capability*	S/N (weighting network)
PHONO 1, 2	2,5 mV	50 kΩ	300 mV	greater than 70 dB (B)
AUX 1, 2 TAPE 1, 2 REC/PB (input) EXT ADPT 1, 2 (input)	150 mV	100 kΩ		greater than 90 dB (A)

<sup>\*</sup> The maximum input capability is measured at a 0.05 % harmonic distortion.

# Outputs

	Output voltage	Impedance
REC OUT 1, 2	150 mV	4.7 kΩ
PRE OUTPUT	1 V	3kΩ
REC/PB	17 mV	82 kΩ
EXT ADPT 1, 2	150 mV	4.7 kΩ

#### Specification Label:

# USA model

SONY®	INTEGRATED	STEREO	AMPLIFIER
	AC 120V SERIAL NO.	60Hz	130 W
		MADE	IN JAPAN

## AEP model

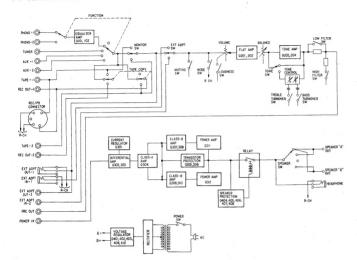
INTEGRATED STEREO AMPLIFIER SONY MODEL NO. TA-4650 AC 110.127.220.240V~ 50/60Hz 270W SERIAL NO. MADE IN JAPAN

# E model

INTEGRATED STEREO AMPLIFIER SONY MODEL NO. TA = 4650 AC 100.120.220.240V 50/60Hz 270W SERIAL NO. MADE IN JAPAN

# SECTION 1

## 1-1. BLOCK DIAGRAM



# SECTION 2 ADJUSTMENTS

# Note: Turn POWER on and allow about three minutes for warm-up,

# 2-1. POWER SUPPLY VOLTAGE ADJUSTMENT

See Fig. 2-1 and 2-2.

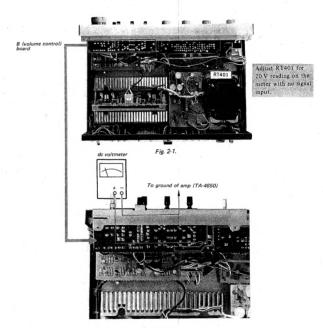


Fig. 2-2.

# 2-2. DC BIAS ADJUSTMENT

Adjust RT301 and RT351 for 75 mV reading on the meter with no signal input.

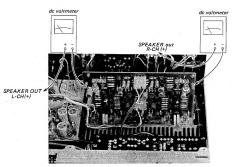
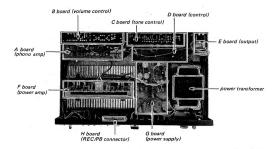


Fig. 2-3.

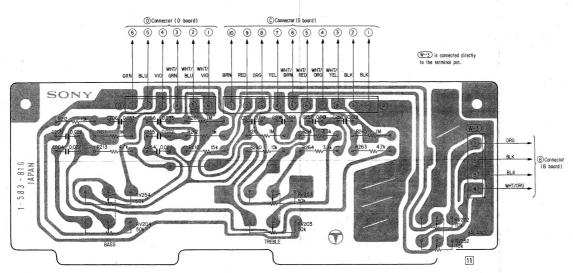
# 2-3. CHASSIS LAYOUT



MEMO				
	***************************************	 	 	

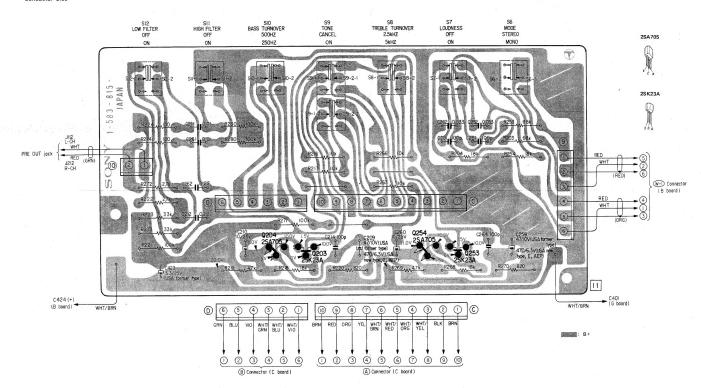
# SECTION 3 DIAGRAMS

# 3-1. MOUNTING DIAGRAM - C Board (tone control) -



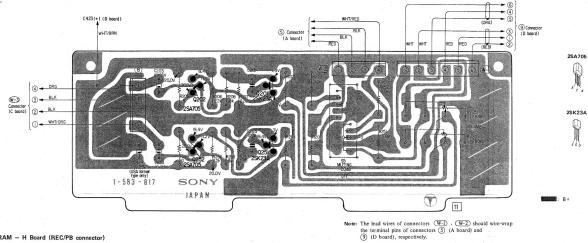
Note: The lead wires of connector (W-3) should wire-wrap the terminal pins of connector (8) on B board.

#### 3-2. MOUNTING DIAGRAM - D Board (control) -

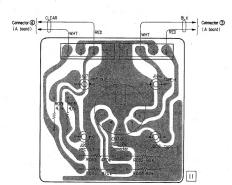


# 3-3. MOUNTING DIAGRAM - B Board (volume control) -

- Conductor Side -



# 3-4. MOUNTING DIAGRAM - H Board (REC/PB connector)

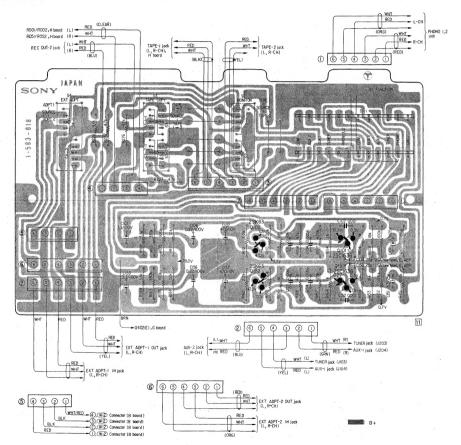


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# TA-4650 TA-4650

# 3-5. MOUNTING DIAGRAM - A Board (phono amp) -

- Conductor Side -

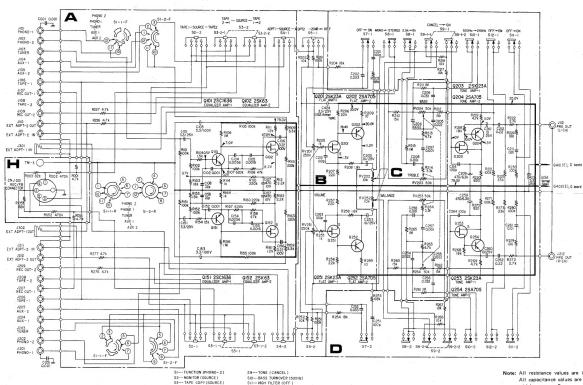


2SK63

2SC1636

#### TA-4650 TA-4650

#### 3-6. SCHEMATIC DIAGRAM - Preamplifier Section -



SI2--- LOW FILTER (OFF)

Note: All resistance values are in ohms, k = 1,000, M = 1,000 k. All capacitance values are in µF except as indicated with p, which means uuF.

All voltages are dc measured with a VOM which has an input impedance of 20k ohms/volt. No signal in.

Voltage variations may be noted because of normal production tolerances.

S3--- TAPE COPY (SOURCE)

S4-EXT ADPT (SOURCE)

S8--TREBLE TURNOVER(2.5kHz)

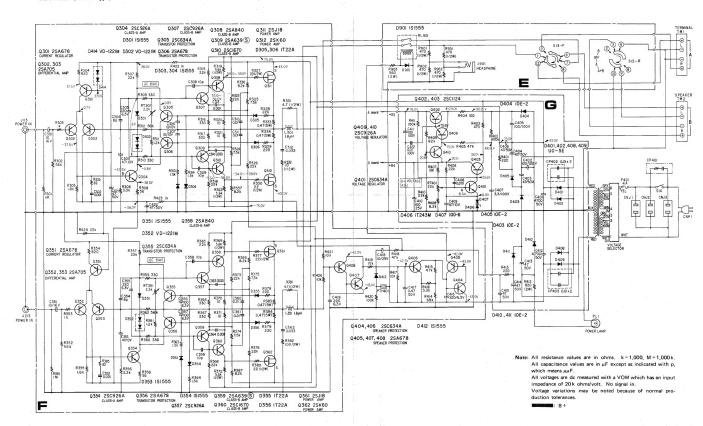
S5--MUTING (OFF)

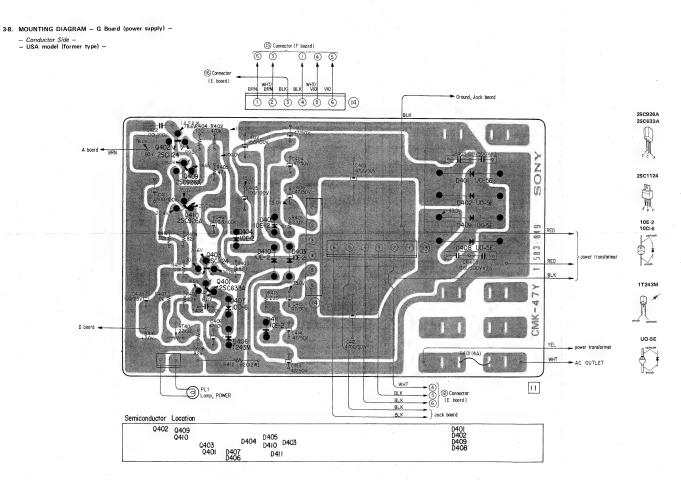
\$6--- MODE (STERED)

S7--- LOUDNESS (OFF)

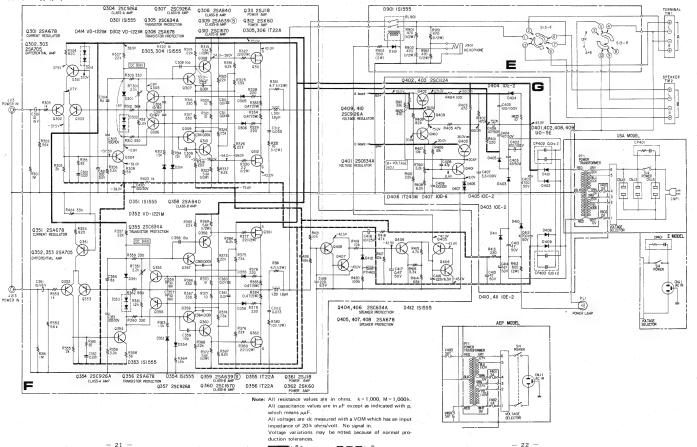
# TA-4650 TA-4650

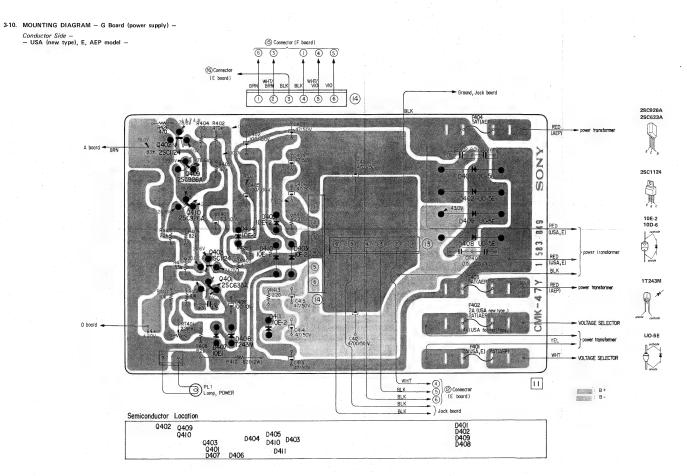
# 3-7. SCHEMATIC DIAGRAM — Power Amplifier Section — — USA model (former type) —



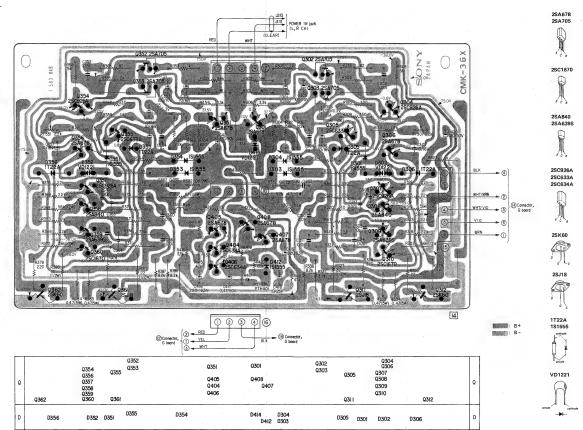


#### 3-9. SCHEMATIC DIAGRAM - Power Amplifier Section -- USA (new type), E, AEP model

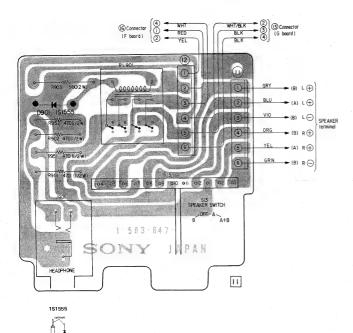




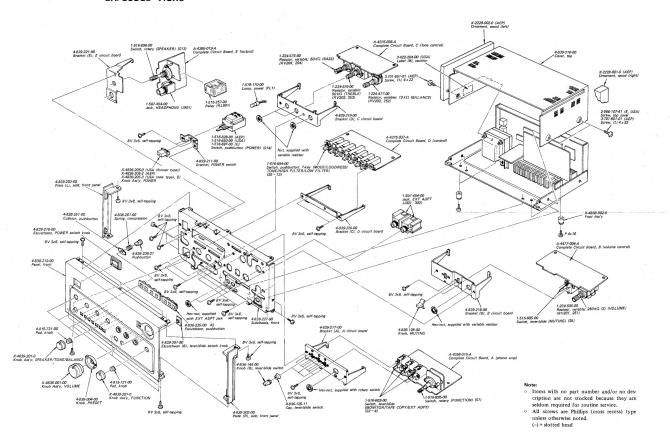
# 3-11. MOUNTING DIAGRAM - F Board (power amp) -

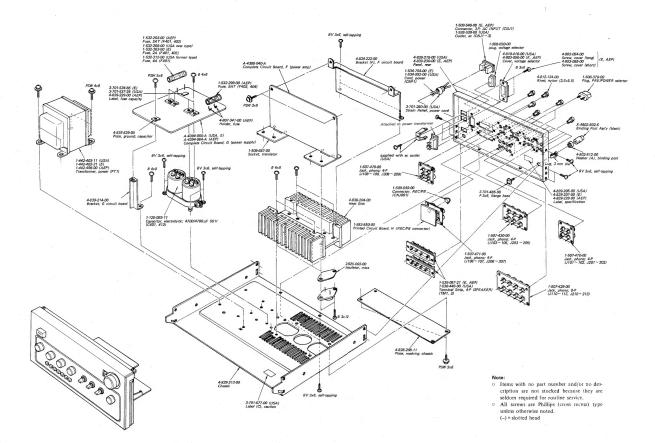


# 3-12. MOUNTING DIAGRAM - E Board (output) -



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# SECTION 5 ELECTRICAL PARTS LIST

									1
Ref. No. Part No. Description	Ref. No. Part No. Description	Ref. No. Part No.		Description	Ref. No.	Part No.		Description	
	Q404 2SC634A	C104(C154) 1-105-510-12	0.0056	mylar	C402	1-123-084-11	100	100 V	
CIRCUIT BOARDS		C105(C155) 1-106-006-12	0.0036	mylar	C402 C403.C404		47	50 V	
	Q405 2SA678								
Note: For USA model, former and new B, D, F and G boards		C106(C156) 1-105-729-12	0.22	100 V mylar	C405	1-123-084-11	100	100 V	
are interchangeable respectively.	Q407,Q408 2SA678	C107(C157) 1-121-425-11	470	10 V	C406	1-123-058-11	47	50 V	
	Q409,Q410 2SC926A								
A-4358-019-A A (phono amp), complete		C201(C251) 1-102-973-11	100 p	ceramic	C407	1-121-995-11	3.3	100 V	
A-4477-004-A B (volume control), complete		C202(C252) 1-105-679-12	0.033	mylar		[1-105-661-12	0.001	mylar (USA	
A-4375-036-A C (tone control), complete		C203(C253) 1-121-748-11	10	25 V	C408			(former type))	
A-4375-037-A D (control), complete	Diodes	C204(C254) 1-105-677-12	0.022	mylar		1-101-881-11	47 p (U	SA (new type), E, AEP	
A-4385-019-A E (output), complete		C205(C255) 1-105-677-12	0.022	mylar				model)	
A-4388-040-A F. (power amp), complete	D301(D351) 1S1555					(1-121-352-11	47	10 V (USA (former type))	
A-4394-050-A G (power supply), complete	D302(D352) VD1221M	C206(C256) 1-105-679-12	0.033	mylar	C409	1-121-414-11		10 V (USA (new type), E,	
(USA, E model)	D303(D353) 1S1555	C207(C257) 1-105-661-12	0.001	mylar		(1 121 111 11	100	AEP model)	
A-4394-064-A G (power supply), complete	D304(D354) 1S1555	C208(C258) 1-105-661-12	0.001	mylar	C410	1-121-935-11	100		
(AEP model)	D305(D355) 1T22A	C206(C256) 1-105-001-12	47	10 V (USA (former type))		1-123-084-11	100	25 V (USA (former type))	
1-583-850-00 H (REC/PB connector)	D306(D356) 1T22A				C411	1-123-084-11	100	100 V (USA (former type))	1
1-583-850-00 H (REC/PB connector)	D300(D330) 1122A	(1-121-424-11	470	6.3 V (USA (new type), E,					
	D401.D402 UO-SE			AEP model)	C412	1-125-093-11	4700	50 V	
		C210(C260) 1-121-748-11	10	25 V		5 1-123-058-11	47	50 V	
	D403~D405 10E-2				C416	1-121-419-11		6.3 V	
	D406 1T243M	C211(C261) 1-105-673-12	0.01	mylar	C417	1-121-726-11		50 V	
SEMICONDUCTORS	D407 10D-6	C212(C262) 1-105-689-12	0.22	mylar	C418	1-121-398-11	10	25 V	
	D408,D409 UO-5E	C213(C263) 1-102-973-11	100 p	ceramic					
Transistors		C214(C264) 1-102-973-11	100 p	ceramic	C419	1-121-419-11	220	6.3 V	
	D410,D411 10E-2				C420,C421	(1-121-411-11	47	50 V (USA (former type))	
Q101(Q151) 2SC1636	D412,D413 1S1555	C301(C351) 1-121-916-11	10	16 V	C420,C421	1-121-417-00	100	50 V (USA (new type), E,	
Q102(Q152) 2SK63 (FET)	D414 VD1221	C302(C352) 1-105-661-12	0.001	mylar				AEP model)	
		C303(C353) {1-121-352-11	47	10 V (USA (former type))	C423.C424	1-121-392-11	3.3	25 V (USA (former type))	
Q201(Q251) 2SK23A (FET)	D901 1S1555	C303(C353) 1-121-414-11	100	10 V (USA (new type), E,					
Q202(Q252) 2SA705				AEP model)					
O203(O253) 2SK23A (FET) -		C304(C354) 1-102-945-11	8 p	ceramic		DEC	STORS		
Q204(Q254) 2SA705		C305(C355) 1-121-419-11	220	6.3 V (USA (former type))		, inco	310110		
254(0254)	TRANSFORMER AND INDUCTORS	0303(0333) 1-121-413-11	220	0.5 v (osis (totilier type))	A11	societore are in O	1/ W ± 6	%, carbon resistors	
Q301(Q351) 2SA678	THANSFORMEN AND INDUCTORS	4 101 410 11	100	( 231 (710 ) ( (		ept special type)			1
	L301(L351) 1-407-592-00 Microinductor, 1.8 µH	C306(C356) {1-121-413-11		6.3 V (USA (former type))				he resistance values.	
Q302(Q352) 2SA705 Q303(Q353) 2SA705	PT1 1-442-403-11 Transformer, power (USA model)	1-121-651-11	10	16 V (USA (new type), E,		1,000, M = 1,000			
				AEP model)					
Q304(Q354) 2SC926A	1-442-403-21 Transformer, power (E model)	C307(C357) (1-121-413-11		6.3 V (USA (former type))					
Q305(Q355) 2SC634A	1-442-496-00 Transformer, power (AEP model)	(1-121-651-11	. 10	16 V (USA (new type), E,	R331(R38	1) 1-202-517-11	4.7	1/2 W composition	
				AEP model)	R332(R38	2) 1-202-525-11	10	1/2 W composition	
Q306(Q356) 2SA678	A	C308(C358) 1-102-947-11	10 p	ceramic	R333(R38	3) 1-217-158-11	0.47	5 W metal	
Q307(Q357) 2SC926A	CAPACITORS	C309(C359) 1-102-947-11	10 p	ceramic	R334(R38	4) 1-217-158-11	0.47	5 W metal	
Q308(Q358) 2SA840		C310(C360) 1-105-673-12	0.01	mylar					
Q309(Q359) 2SA639S	Capacitors are in μF, electrolytic type unless			-	R412	1-206-662-11	820	2 W metal-oxide	
Q310(Q360) 2SC1670	otherwise noted. ( $p=\mu\mu$ ) The working voltage of 50	C311(C361) 1-105-673-12	0.01	mylar	R 901 (R 95	1) 1-202-565-11	470	1/2 W composition	
	volts or less are omitted except for electrolytic type.	C312(C362), 1-105-679-12	0.033	mylar		2) 1-202-565-11	470	1/2 W composition	
Q311(Q361) 2SJ18 (FET)		C313(C363) 1-105-661-12	0.001	mylar	R903	1-206-658-11		2 W metal-oxide	
Q312(Q362) 2SK60 (FET)	C001(C051) 1-102-074-11 0.001 ceramic	C314(C364) 1-105-661-12	0.001	mylar	1.703	1 200 030-11	500	2 ii iiiciai oxido	
O401 2SC634A	C101(C151) 1-121-913-11 3.3 25 V	C31-(C30+) 1-103-001-12	0.001	mytar	RT301				
Q402,Q403 2SC1124	C102(C152) 1-105-661-12 0.001 mylar	C401 1-125-093-11	4700	50 V	(RT351)	1-224-489-00	2.2 k, a	djustable (dc bias adj.)	
4.0014.00	1 CLOSECTOS, A LOG COL LE CICCLE HIJEL	1-125-095-11	4700	30 V	(K1351)				

Ref. No.	Part No.	Description	Ref. No.	Part No.	Description
RT401 (RV201 (RV251) (RV202 (RV252) (RV203 (RV253) (RV253) (RV254)	1-224-250-00 1-224-505-00 1-224-577-00 1-224-576-00 1-224-575-00	2.2 k, adjustable (power voltage adj.) 250k(S), variable (VOLUME) 10k, variable (BALANCE) 50k, variable (TREBLE) 50k, variable (BASS)	CNJ1~CNJ CNP1 CP401 CP402 CP403 F401,F402	3 1-526-528-00 {1-534-754-00 1-534-992-00 1-231-057-31 1-102-355-11 {1-532-203-00 1-532-268-00	Outlet, ac (USA model) Cord, power (E model) Cord, power (USA model) Encapsulated Component (USA, E model) Capacitor, ceramic 0.01 µF 500 V Fuse, 2AT (AEP model) Fuse, 2A (USA model (new type))
S1	1-516-695-00	TCHES  Rotary (FUNCTION)	F401,F402 F401 F403,F404	1-532-363-00 1-532-312-00	Fuse, 2A (USA model (new type)) Fuse, 2A (E model) Fuse, 4A (USA model (former type)) Fuse, 5AT (AEP model)
\$2~\$4 \$5 \$6~\$12 \$13	1-516-693-00 1-516-694-00 1-516-694-00 1-516-698-00 1-516-693-00 1-516-697-00	Lever/Silde (MONITOR, TAPE COPY, EXT ADPT) Lever/Silde (MUTING) Pushbutton, 7-key (MODE, LOUDNESS, TONE, HIGH FILTER, LOW FILTER) Rotary (SPEAKER) Pushbutton (POWER) (AEP model) Pushbutton (FOWER) (USA model) Pushbutton (FOWER) (E model)	PL1 Pth401 RL901 TM1,TM2	1-518-170-00 1-800-340-00 1-515-257-00 {1-535-057-21 1-536-446-00 1-506-370-00 1-508-690-00 1-509-667-00 1-536-354-00	Lamp, power Thermistor (positive) Relay Terminal Strip, 4-P (SPEAKER) (E, AEP model) Terminal Strip, 4-P (SPEAKER) (USA model) Plug, PRE/POWER selector Plug, voltage selector (USA model) Socket, transistor Pin, terminal
	JA	ACKS	-		

(J103~J105 (J203~J205)	1-507-430-00	Phono, 6-P	ACCESSORIES A
(J206,J207)	1-507-471-00	Phono, 4-P	Part No.
(J208,J209)	1-507-470-00	Phono, 4-P	X-3701-029-0 1-506-113-00
			3-429-126-00
(J110~J113 (J210~J213)	1-507-429-00	Phono, 8-P	3-701-020-00
J301,J302	1-507-454-00	EXT ADPT	3-701-730-00
J901	1-507-454-00	HEADPHONE	3-701-742-00
			3-780-508-21
			3-780-508-11
	MISCELI	ANEOUS	

Connector, 3-P; AC INPUT (E, AEP

(J201,J202) 1-507-470-00 Phono, 4-P

1-509-546-00

1-509-549-00 Connector, REC/PB

model)

CNJ001

CNJ1

Part No.	Description
X-3701-029-0	Card Ass'y, warranty
1-506-113-00	Plug, shorting
3-429-126-00	Bag, polyethylene; unit
3-701-020-00	Bag, polyethylene; instruction manual
3-701-730-00	Bag, polyethylene; IBM card
3-701-742-00	Card, IBM
3-780-508-21	Manual, instruction (USA model
3-780-508-11	Manual, instruction (AEP model
	Manual, instruction (E model)
3-793-807-11	Schematic Diagram
4-839-225-00	Carton
4-839-226-00	Cushion